

### PATENT APPLICATION

# IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re application of

Docket No: Q66212

KIYOKU, HIROYUKI, et al.

Application No.: 09/986,332

Confirmation No.: 5542

Group Art Unit: 1765

Filed: November 8, 2001

Examiner: Anderson, Matthew A.

For:

NITRIDE SEMICONDUCTOR GROWTH METHOD, NITRIDE SEMICONDUCTOR

SUBSTRATE, AND NITRIDE SEMICONDUCTOR DEVICE

## AMENDMENT UNDER 37 C.F.R. § 1.114(c)

#### MAIL STOP RCE

Commissioner for Patents P.O. Box 1450 Alexandria, VA 22313-1450

Sir:

In response to the Office Action dated September 25, 2003, please amend the aboveidentified application as follows on the accompanying pages.

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